30A, 50V - 600V Super Fast Rectifier

FEATURES

- AEC-Q101 qualified available
- Dual rectifier construction, positive center-tap
- Glass passivated chip junctions
- Superfast recovery time, high voltage
- Low forward voltage, high current capability
- Low thermal resistance
- Low power loss, high efficiency
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

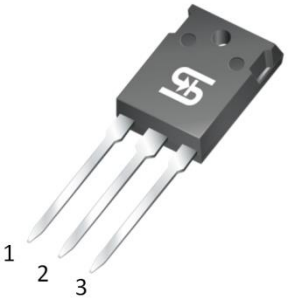
KEY PARAMETERS		
PARAMETER	**VALUE**	**UNIT**
I_F	30	A
V_{RRM}	50 - 600	V
I_{FSM}	300	A
$T_{J\,MAX}$	150	°C
Package	TO-247AD (TO-3P)	
Configuration	Dual dies	

APPLICATIONS

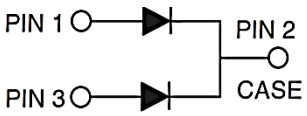
- DC to DC converter
- Switching mode converters and inverters
- Lighting application
- Snubber
- Freewheeling application

MECHANICAL DATA

- Case: TO-247AD (TO-3P)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 301 class 2 whisker test
- Mounting torque: 1.13 N·m maximum
- Polarity: As marked
- Weight: 5.60g (approximately)



TO-247AD (TO-3P)



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

PARAMETER	SYMBOL	SF 3001 PT	SF 3002 PT	SF 3003 PT	SF 3004 PT	SF 3005 PT	SF 3006 PT	SF 3008 PT	UNIT
Marking code on the device		SF 3001 PT	SF 3002 PT	SF 3003 PT	SF 3004 PT	SF 3005 PT	SF 3006 PT	SF 3008 PT	
Repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	600	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	105	140	210	280	420	V
Forward current	I_F	30							A
Surge peak forward current 8.3ms single half sine wave superimposed on rated load	I_{FSM}	300							A
Junction temperature	T_J	-55 to +150							°C
Storage temperature	T_{STG}	-55 to +150							°C

THERMAL PERFORMANCE

PARAMETER	SYMBOL	TYP	UNIT
Junction-to-case thermal resistance	$R_{\Theta JC}$	1	°C/W

ELECTRICAL SPECIFICATIONS (T_A = 25°C unless otherwise noted)

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage per diode[1]	SF3001PT SF3002PT SF3003PT SF3004PT	I_F = 15A, T_J = 25°C	V_F	-	0.95	V
	SF3005PT SF3006PT			-	1.30	V
	SF3008PT			-	1.70	V
Reverse current @ rated V_R per diode[2]		T_J = 25°C	I_R	-	10	μA
		T_J = 125°C		-	500	μA
Junction capacitance per diode		1MHz, V_R = 4.0V	C_J	175	-	pF
Reverse recovery time		I_F = 0.5A, I_R = 1.0A I_{rr} = 0.25A	t_{rr}	-	35	ns

Notes:

1. Pulse test with PW = 0.3ms
2. Pulse test with PW = 30ms

ORDERING INFORMATION

ORDERING CODE[1][2]	PACKAGE	PACKING
SF30xPT	TO-247AD (TO-3P)	30 / Tube
SF30xPTH	TO-247AD (TO-3P)	30 / Tube

Notes:

1. “x” defines voltage from 50V(SF3001PT) to 600V(SF3008PT)
2. “H” means AEC-Q101 qualified

CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve

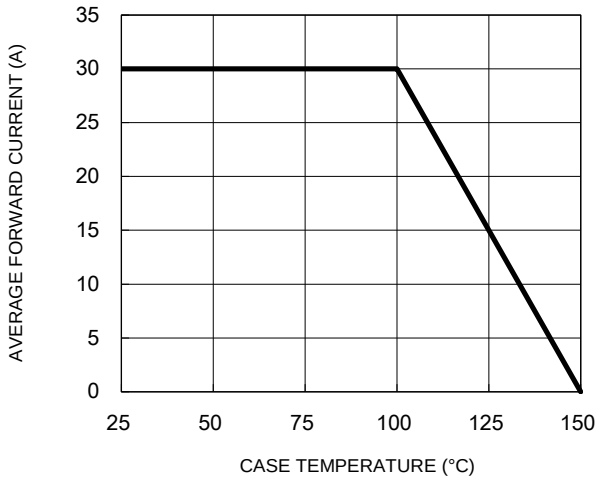


Fig.2 Typical Junction Capacitance

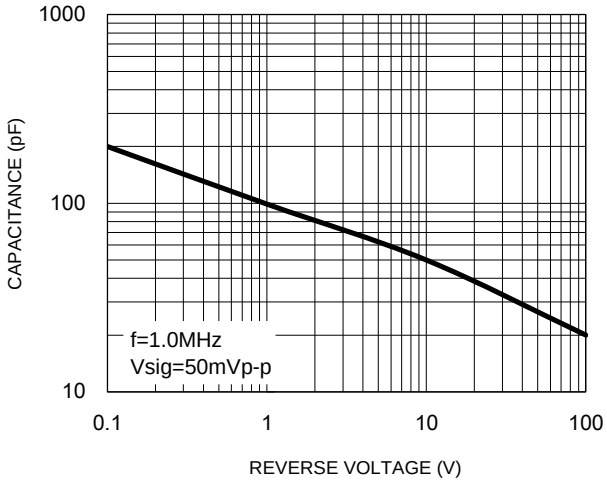


Fig.3 Typical Reverse Characteristics

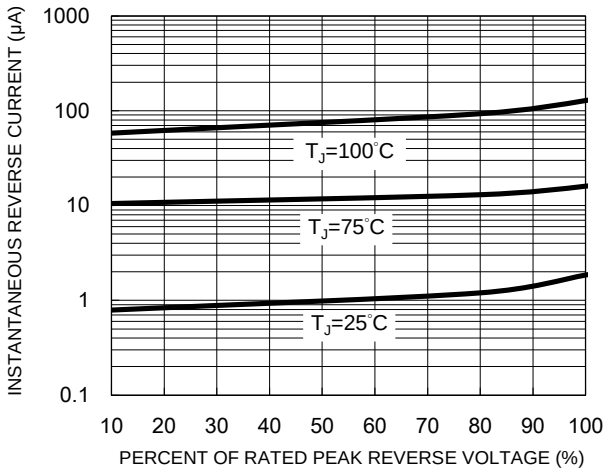


Fig.4 Typical Forward Characteristics

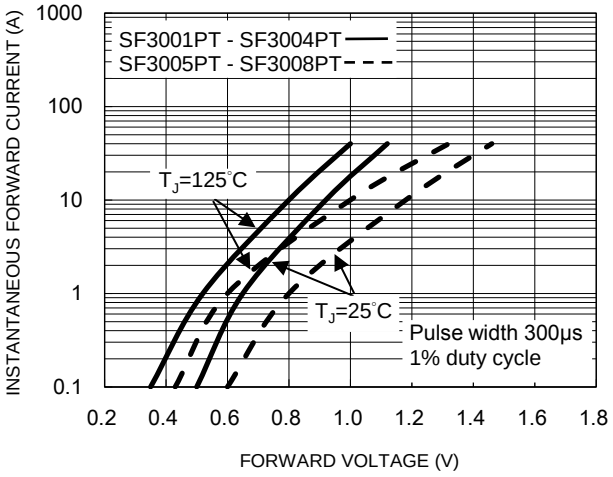
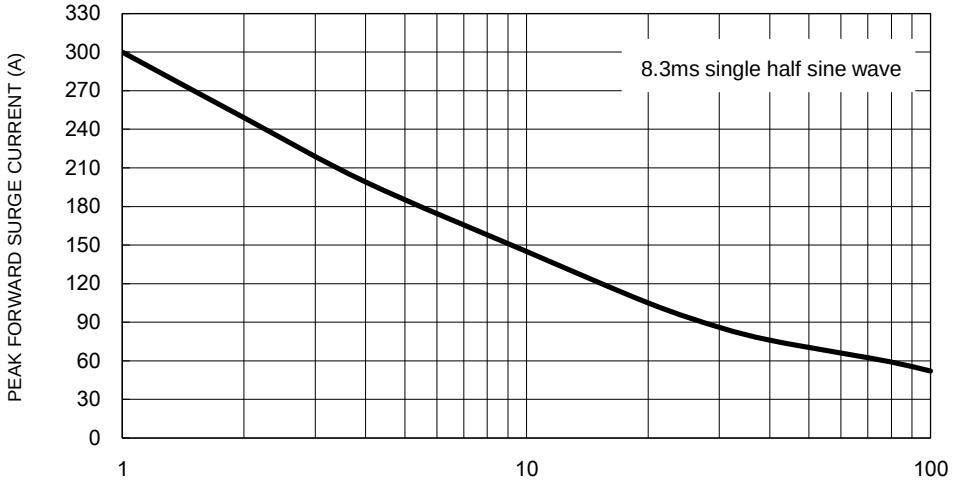


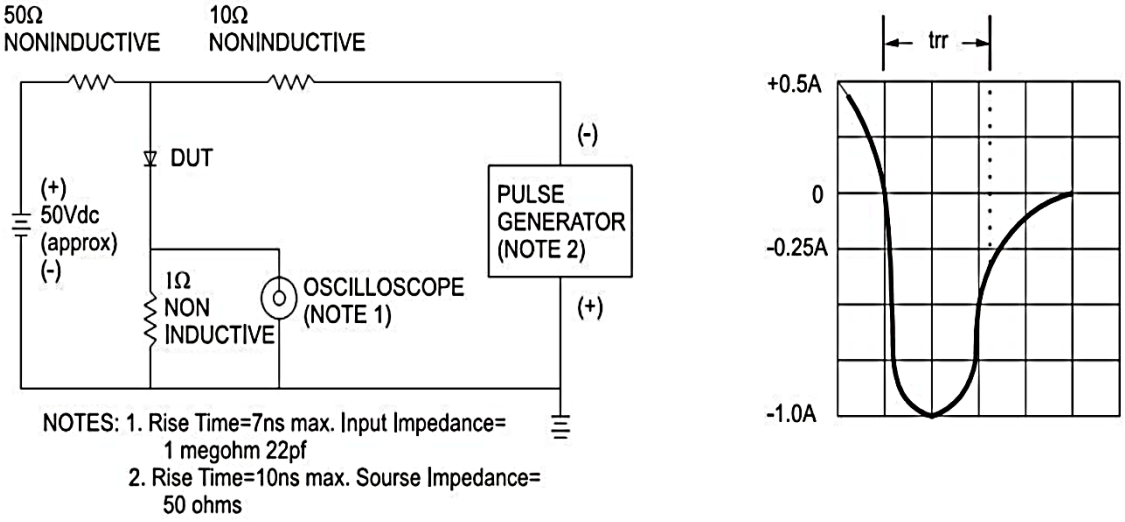
Fig.5 Maximum Non-Repetitive Forward Surge Current



CHARACTERISTICS CURVES

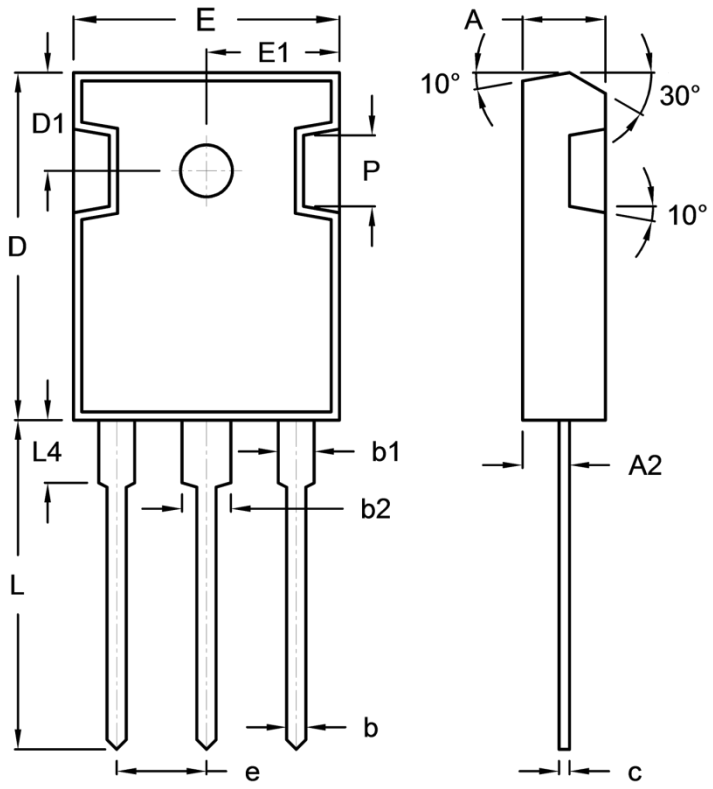
(T_A = 25°C unless otherwise noted)

Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram



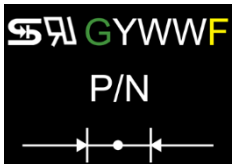
PACKAGE OUTLINE DIMENSIONS

TO-247AD (TO-3P)



DIM	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	4.90	5.16	0.193	0.203
A2	2.70	3.00	0.106	0.118
b	1.12	1.22	0.044	0.048
b1	1.93	2.18	0.076	0.086
b2	2.97	3.22	0.117	0.127
c	0.51	0.76	0.020	0.030
D	20.80	21.30	0.819	0.839
D1	5.70	6.20	0.224	0.244
E	15.90	16.40	0.626	0.646
E1	7.90	8.20	0.311	0.323
e	5.20	5.70	0.205	0.224
H	2.90	3.40	0.114	0.134
L	19.70	20.20	0.776	0.795
L4	3.50	4.10	0.138	0.161
P	-	4.30	-	0.169

MARKING DIAGRAM



P/N = Marking Code
G = Green Compound
YWW = Date Code
F = Factory Code